

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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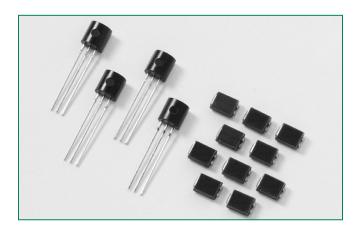








ROHS EC103xx & SxSx Series



Description

Excellent unidirectional switches for phase control applications such as heating and motor speed controls.

Sensitive gate SCRs are easily triggered with microAmps of current as furnished by sense coils, proximity switches, and microprocessors.

Features & Benefits

- RoHS compliant
- Glass passivated junctions
- Voltage capability up to 600 V
- Surge capability up to 20 A

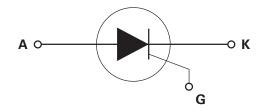
Main Features

| Symbol | Value | Unit |
|---------------------|------------|------|
| I _{T(RMS)} | 0.8 | А |
| V_{DRM}/V_{RRM} | 400 to 600 | V |
| I _{GT} | 12 to 500 | μΑ |

Applications

Typical applications are capacitive discharge systems for strobe lights and gas engine ignition. Also controls for power tools, home/brown goods and white goods appliances.

Schematic Symbol



Absolute Maximum Ratings — Sensitive SCRs

| Symbol | Parameter | Test Conditions | Value | Unit | |
|---------------------|---|---|------------|------------------|--|
| I _{T(RMS)} | RMS on-state current | T _c = 75°C | 0.8 | А | |
| I _{T(AV)} | Average on-state current | T _C = 75°C | 0.51 | А | |
| 1 | Peak non-repetitive surge current | single half cycle; f = 50Hz; T _J (initial) = 25°C | 16 | | |
| I _{TSM} | reak non-repetitive surge current | single half cycle; f = 60Hz; T _J (initial) = 25°C | 20 | А | |
| l²t | I²t Value for fusing | t _p = 8.3 ms | 1.6 | A ² s | |
| di/dt | Critical rate of rise of on-state current | f = 60 Hz ; T _J = 110°C | 50 | A/µs | |
| I _{GM} | Peak gate current | T _J = 110°C | 1 | А | |
| P _{G(AV)} | Average gate power dissipation | T _J = 110°C | 0.1 | W | |
| T _{stg} | Storage temperature range | | -40 to 150 | °C | |
| T _J | Operating junction temperature range | | -40 to 110 | °C | |

Teccor® brand Thyristors 0.8 Amp Sensitive SCRs



Electrical Characteristics (T_J = 25°C, unless otherwise specified)

| | | | | Value | | | | |
|-----------------|---|-----------------|---------|-------|---|------|-----|-------|
| Symbol | Test Conditions | Test Conditions | | | SxS1 SxS2 SxS SxS3 SxS3 SxS3 SxS3 SxS3 SxS3 | | | |
| I _{GT} | V - 6V: B - 100 O | | MAX. | 12 | 50 | 200 | 500 | μΑ |
| $V_{\rm GT}$ | $V_D = 6V; R_L = 100 \Omega$ | | MAX. | 0.8 | | | | V |
| dv./d+ | V V . B 1k0 | 400V | MIN. | 20 | 25 | 30 | 40 | 1//// |
| dv/dt | $V_{D} = V_{DRM}$; $R_{GK} = 1k\Omega$ | 600V | IVIIIN. | 10 | 10 | 15 | 20 | V/µs |
| V _{GD} | $V_{D} = V_{DRM}$; $R_{L} = 3.3 \text{ k}\Omega$; $T_{J} = 110^{\circ}\text{C}$ | | MIN. | 0.2 | | 0.25 | | V |
| I _H | $I_{T} = 20 \text{mA}$ (initial), $R_{GK} = 1 \text{k}\Omega$ | | MAX. | | 5 | | 8 | mA |
| t _q | (1) MAX. | | 6 | 0 | 50 | 45 | μs | |
| t _{gt} | $I_{G} = 2 \times I_{GT'}$ PW = 15 μ s; $I_{T} = 1.6A$ | | TYP. | 2 | 5 | 20 | 30 | μs |

⁽¹⁾ $I_T = 1A$; $t_p = 50\mu s$; $dv/dt = 5V/\mu s$; $di/dt = -5A/\mu s$

Static Characteristics

| Symbol | | Value | Unit | | |
|-------------------------------------|---|------------------------|------|-----|----|
| V _{TM} | $I_{T} = 1.2A; t_{p} = 380 \mu s$ | | MAX. | 1.7 | V |
| | | T _J = 25°C | | 1 | |
| I _{DRM} / I _{RRM} | I_{RRM} $V_{DRM} = V_{RRM}$ $R_{GK} = 1k\Omega$ | T _J = 100°C | MAX. | 50 | μΑ |
| | GK 1.132 | T _J = 110°C | | 100 | |

Thermal Resistances

| Symbol | Parameter | Value | Unit | |
|-------------------|-----------------------|----------------|------|------|
| D | EC103xy/2N6565 75 | | °C/W | |
| $R_{\theta(J-C)}$ | Junction to case (AC) | SxSy | 60* | C/VV |
| $R_{\theta(J-A)}$ | Junction to ambient | EC103xy/2N6565 | 160 | °C/W |

Notes: x = voltage, y = sensitivity

^{* =} Mounted on 1 cm² copper (two-ounce) foil surface



Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

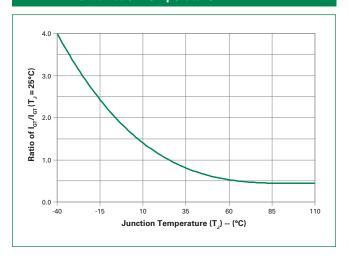


Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature

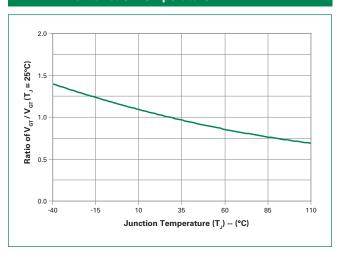


Figure 3: Normalized DC Holding Current vs. Junction Temperature

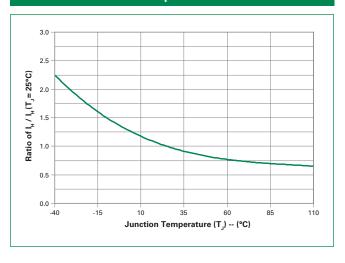


Figure 4: On-State Current vs. On-State Voltage (Typical)

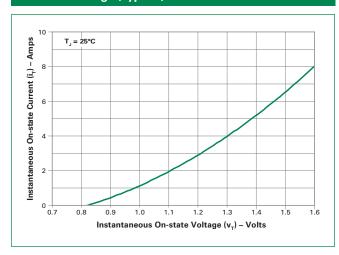


Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

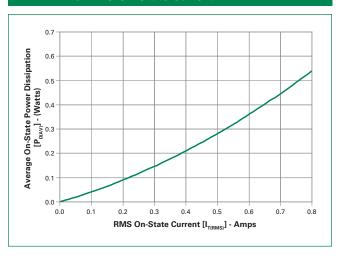


Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current

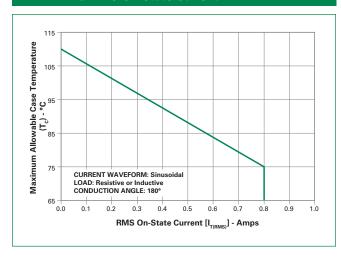




Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current

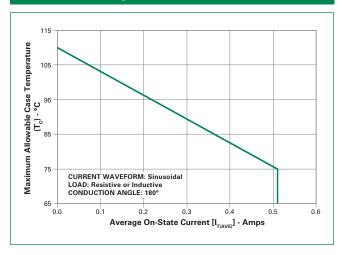


Figure 8: Maximum Allowable Ambient Temperature vs. RMS On-State Current

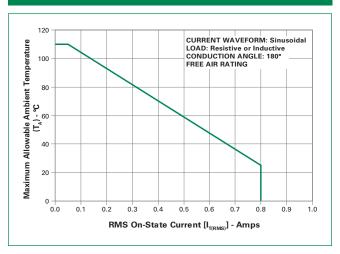


Figure 9: Maximum Allowable Ambient Temperature vs. Average On-State Current

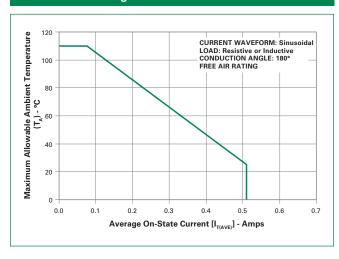


Figure 10: Peak Capacitor Discharge Current

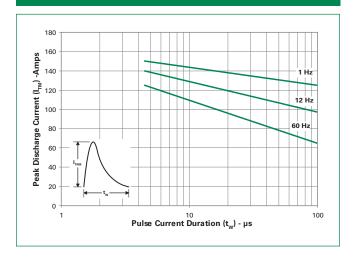


Figure 11: Peak Repetitive Sinusoidal Pulse Current

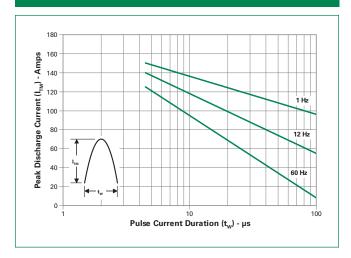
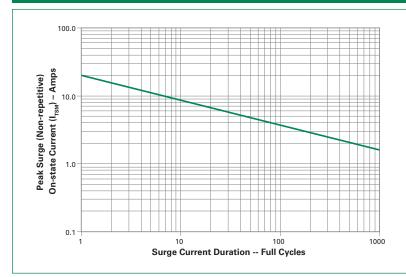




Figure 12: Surge Peak On-State Current vs. Number of Cycles



SUPPLY FREQUENCY: 60 Hz Sinusoidal

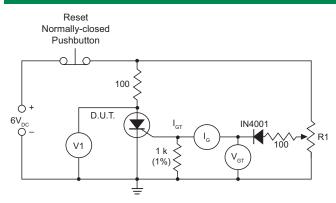
LOAD: Resistive

RMS On-State Current: $[I_{T(RMS)}]$: Maximum Rated Value at Specified Case Temperature

Notes:

- 1. Gate control may be lost during and immediately following surge current interval.
- 2. Overload may not be repeated until junction temperature has returned to steady-state rated value.

Figure 13: Simple Test Circuit for Gate Trigger Voltage and Current



Note: V1 - 0 V to 10 V dc meter

 $V_{\rm GT} = 0 \, {\rm V}$ to 1 V dc meter $I_{\rm G} = 0 \, {\rm mA}$ to 1 mA dc milliammeter

R1 — 1 k potentiometer

To measure gate trigger voltage and current, raise gate voltage $(V_{\rm GT})$ until meter reading V1 drops from 6 V to 1 V. Gate trigger voltage is the reading on $V_{\rm GT}$ just prior to V1 dropping. Gate trigger current Ig Can be computed from the relationship

$$I_{\text{GT}} = I_{\text{G}} - \frac{V_{\text{GT}}}{1000} \text{Amps}$$

where I_G is reading (in amperes) on meter just prior to V1 dropping

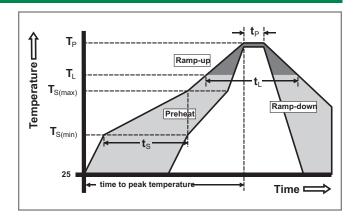
Note: I_{GT} may turn out to be a negative quantity (trigger current flows out from gate lead). If negative current occurs, $I_{\rm gT}$ value is not a valid reading. Remove 1 k resistor and use $l_{\rm g}$ as the more correct $l_{\rm g}$ value. This will occur on 12 μA gate products.

Teccor® brand Thyristors 0.8 Amp Sensitive SCRs



Soldering Parameters

| Reflow Co | ndition | Pb – Free assembly | |
|---------------------------------------|--|-------------------------|--|
| | -Temperature Min (T _{s(min)}) | 150°C | |
| Pre Heat | -Temperature Max (T _{s(max)}) | 200°C | |
| | -Time (min to max) (t _s) | 60 – 180 secs | |
| Average ra | amp up rate (LiquidusTemp) k | 5°C/second max | |
| T _{S(max)} to T _L | - Ramp-up Rate | 5°C/second max | |
| Reflow | -Temperature (T _L) (Liquidus) | 217°C | |
| Reliow | -Temperature (t _L) | 60 – 150 seconds | |
| PeakTemp | perature (T _P) | 260 ^{+0/-5} °C | |
| Time with Temperate | in 5°C of actual peak ure (t _p) | 20 - 40 seconds | |
| Ramp-dov | vn Rate | 5°C/second max | |
| Time 25°C | to peakTemperature (T _P) | 8 minutes Max. | |
| Do not exc | ceed | 280°C | |



Physical Specifications

| Terminal Finish | 100% Matte Tin-plated/Pb-free Solder Dipped | |
|-----------------|---|--|
| Body Material | UL recognized epoxy meeting flammability classification 94V-0 | |
| Lead Material | Copper Alloy | |

Design Considerations

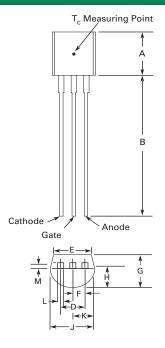
Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

| Test | Specifications and Conditions | | | |
|---------------------------|--|--|--|--|
| AC Blocking | MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 110°C for 1008 hours | | | |
| Temperature Cycling | MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time | | | |
| Temperature/ Humidity | EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity | | | |
| High Temp Storage | MIL-STD-750, M-1031, 1008 hours; 150°C | | | |
| Low-Temp Storage | 1008 hours; -40°C | | | |
| Thermal Shock | MIL-STD-750, M-1056 10 cycles; 0°C to 100°C; 5-min dwell- time at each temperature; 10 sec (max) transfer time between temperature | | | |
| Autoclave | EIA / JEDEC, JESD22-A102 168 hours (121°C at 2 ATMs) and 100% R/H | | | |
| Resistance to Solder Heat | MIL-STD-750 Method 2031 | | | |
| Solderability | ANSI/J-STD-002, category 3, Test A | | | |
| Lead Bend | MIL-STD-750, M-2036 Cond E | | | |



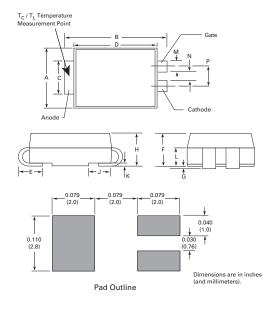
Dimensions - TO-92 (E Package)



| Dimension | Inches | | Mill | imeters |
|-----------|--------|-------|-------|---------|
| Dimension | Min | Max | Min | Max |
| А | 0.176 | 0.196 | 4.47 | 4.98 |
| В | 0.500 | - | 12.70 | - |
| D | 0.095 | 0.105 | 2.41 | 2.67 |
| Е | 0.150 | - | 3.81 | - |
| F | 0.046 | 0.054 | 1.16 | 1.37 |
| G | 0.135 | 0.145 | 3.43 | 3.68 |
| Н | 0.088 | 0.096 | 2.23 | 2.44 |
| J | 0.176 | 0.186 | 4.47 | 4.73 |
| K | 0.088 | 0.096 | 2.23 | 2.44 |
| L | 0.013 | 0.019 | 0.33 | 0.48 |
| M | 0.013 | 0.017 | 0.33 | 0.43 |

All leads insulated from case. Case is electrically nonconductive.

Dimensions — Compak (C Package)



| D: | Inc | hes | Millimeters | | |
|-----------|-------|-------|-------------|------|--|
| Dimension | Min | Max | Min | Max | |
| А | 0.130 | 0.156 | 3.30 | 3.95 | |
| В | 0.201 | 0.220 | 5.10 | 5.60 | |
| С | 0.077 | 0.087 | 1.95 | 2.20 | |
| D | 0.159 | 0.181 | 4.05 | 4.60 | |
| Е | 0.030 | 0.063 | 0.75 | 1.60 | |
| F | 0.075 | 0.096 | 1.90 | 2.45 | |
| G | 0.002 | 0.008 | 0.05 | 0.20 | |
| Н | 0.077 | 0.104 | 1.95 | 2.65 | |
| J | 0.043 | 0.053 | 1.09 | 1.35 | |
| K | 0.006 | 0.016 | 0.15 | 0.41 | |
| L | 0.030 | 0.055 | 0.76 | 1.40 | |
| М | 0.022 | 0.028 | 0.56 | 0.71 | |
| N | 0.027 | 0.033 | 0.69 | 0.84 | |
| Р | 0.052 | 0.058 | 1.32 | 1.47 | |

Teccor® brand Thyristors 0.8 Amp Sensitive SCRs



Product Selector

| Part Number | Voltage | | | Gate Sensitivity | Type | Package | |
|-------------|------------|------|------|------------------|------------------|---------------|---------|
| rait Number | 400V | 600V | 800V | 1000V | Gate Sensitivity | туре | гаскаде |
| EC103 x 1 | X | Χ | | | 12μΑ | Sensitive SCR | TO-92 |
| EC103 x 2 | X | Χ | | | 50μΑ | Sensitive SCR | TO-92 |
| EC103 x | X / 2N6565 | Χ | | | 200μΑ | Sensitive SCR | TO-92 |
| EC103 x 3 | X | Χ | | | 500μΑ | Sensitive SCR | TO-92 |
| S x S1 | X | Χ | | | 12μΑ | Sensitive SCR | Compak |
| S x S2 | X | Χ | | | 50μΑ | Sensitive SCR | Compak |
| SxS | X | Χ | | | 200μΑ | Sensitive SCR | Compak |
| S x S3 | X | Χ | | | 500μΑ | Sensitive SCR | Compak |

Note: x = Voltage

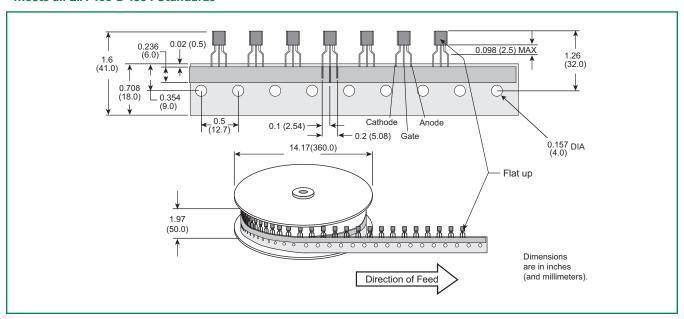
Packing Options

| Part Number | Marking | Weight | Packing Mode | Base Quantity |
|------------------|------------------|--------|------------------|---------------|
| EC103xy / 2N6565 | EC103xy / 2N6565 | 0.19 g | Bulk | 2000 |
| EC103xyRP | EC103xy | 0.19 g | Reel Pack | 2000 |
| EC103xyAP | EC103xy | 0.19 g | Ammo Pack | 2000 |
| SxSyRP | SxSy | 0.08 g | Embossed Carrier | 2500 |

Note: x = Voltage, y = sensitivity

TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications

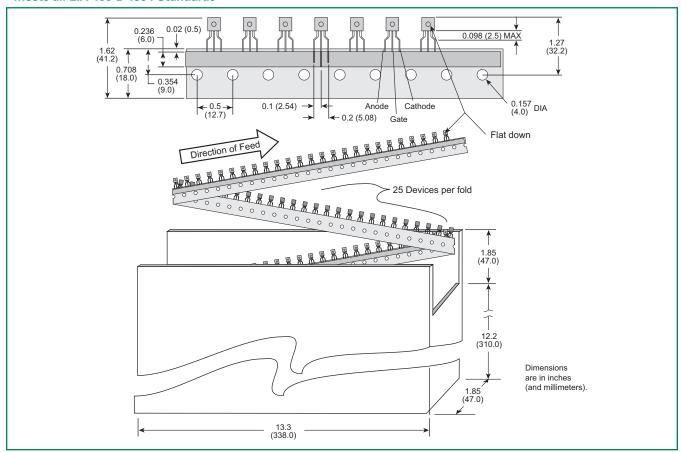
Meets all EIA-468-B 1994 Standards





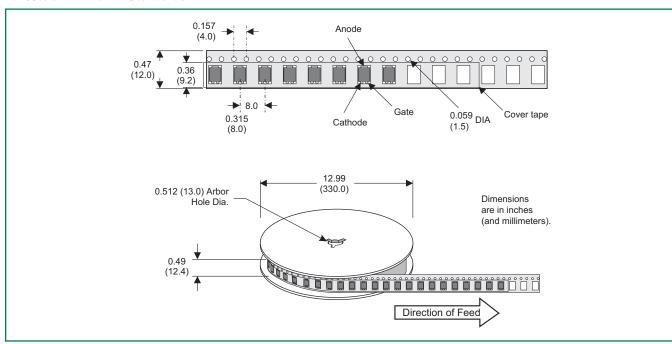
TO-92 (3-lead) Ammo Pack (AP) Radial Leaded Specifications

Meets all EIA-468-B 1994 Standards



Compak Embossed Carrier Reel Pack (RP) Specifications

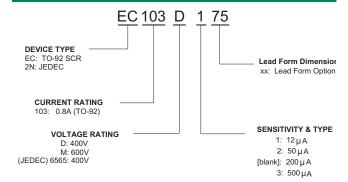
Meets all EIA-481-1 Standards



Teccor® brand Thyristors 0.8 Amp Sensitive SCRs



Part Numbering System (TO-92)

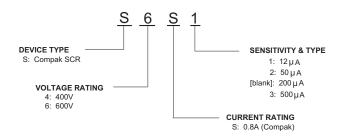


Part Marking System

TO-92 (E Package)



Part Numbering System (Compak)



Part Marking System (Compak)

Compak (C Package)

